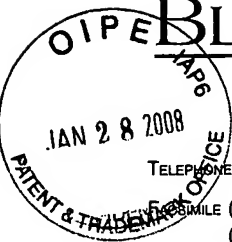


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# BLAKELY SOKOLOFF TAYLOR & ZAFMAN

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January 10, 2008

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Re: **CERTIFICATE OF CORRECTION**  
U. S. Letters Patent No. 7,230,276  
Issued: Jun. 12, 2007  
For: Semiconductor Optical Device Having Current-Confined Structure  
Inventor: Song et al.  
Our File No. 002013.P115

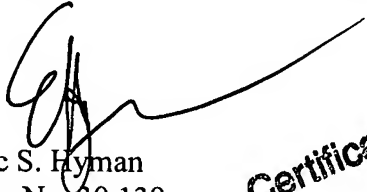
Dear Sir:

Enclosed is a Certificate of Correction (two copies) for the above-referenced patent.

This request for correction is made under rule 322 of the Rules of Practice and 35 U.S.C. Section 254.

Respectfully submitted,

BLAKELY, SOKOLOFF, TAYLOR & ZAFMAN LLP

  
Eric S. Hyman  
Reg. No. 30,139

**Certificate**  
**JAN 30 2008**  
**of Correction**

ESH/ms  
enclosures  
PTO Form- 1449

**UNITED STATES PATENT AND TRADEMARK OFFICE**  
**CERTIFICATE OF CORRECTION**

**PATENT NO: 7,230,276**

**DATED: Jun. 12, 2007**

**INVENTOR(S): Song et al.**

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

In the Claims, please delete claim 15 and insert claim 20 as follows:

"The device of claim 16, wherein the semiconductor layer constituting the gain region is one of a p-type semiconductor layer, an n-type semiconductor layer, and an undoped semiconductor layer."

In Claim #17, line 1, please delete "17 " and insert -- 16 --.

In Claim #18, line 1, please delete "17 " and insert -- 16 --.

In Claim #19, line 1, please delete "17 " and insert -- 16 --.

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**MAILING ADDRESS OF SENDER:**

BLAKELY, SOKOLOFF, TAYLOR & ZAFMAN LLP  
12400 Wilshire Blvd. 7th floor  
Los Angeles, CA 90025-1030

**PATENT NO. 7,230,276**

**Certificate of Correction (PTO Form 1050)-Amended**

**UNITED STATES PATENT AND TRADEMARK OFFICE**  
**CERTIFICATE OF CORRECTION**

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In Claim #18, line 1, please delete "17 " and insert - - 16 - -.

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**PATENT NO. 7,230,276**

**Certificate of Correction (PTO Form 1050)-Amended**

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